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# Theoretical investigation of the ${}^{7}F_{1}$ level splitting in a series of Eu<sup>3+</sup> doped oxides matrixes

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#### Abstract

The point charge electrostatic model (PCEM) and the simple overlap model (SOM) are applied to a series of oxide crystals (Gd<sub>2</sub>O<sub>3</sub>, Y<sub>2</sub>O<sub>3</sub>, Lu<sub>2</sub>O<sub>3</sub>, In<sub>2</sub>O<sub>3</sub> and Sc<sub>2</sub>O<sub>3</sub>) and a silicate glass (Al<sub>2</sub>O<sub>3</sub>–SiO<sub>2</sub>) doped with the Eu<sup>3+</sup> ion. The SOM factor  $\rho(2\beta)^{k+1}$  is input as the shielding factor for all  $B_q^k$  expressions, which enters in the calculations of the crystal-field strength parameter,  $N_V$ . The maximum splitting  $\Delta E$  of the <sup>7</sup>F<sub>1</sub> manifold of the Eu<sup>3+</sup> ion is then obtained as a function of  $N_V$ . It has been developed another way to calculate alpha, which is an expansion factor in the  $\Delta E$  expression. For the glass, as the mean metal-ligating ions distances are larger than for the crystals,  $N_V$  and  $\Delta E$  are smaller, as expected. The prediction of the PCEM shows a linear dependence between  $\Delta E$  and  $N_V$ , even though the known mismatch in respect to the experimental splitting is kept. In the case of the SOM, two situations have been analyzed: firstly the charge factor varies in order to reproduce the experimental splitting (a phenomenological procedure); secondly the charge factor is the valence of the oxygen ions. The agreement between the experimental results and theoretical predictions for all investigated systems is very satisfactory in respect to both the linearity between  $\Delta E$  and  $N_V$  and the  $\Delta E$  splitting. © 2007 Published by Elsevier B.V.

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### 1. Introduction

The effect of the nearest neighbors on the optical behavior of lanthanide  $(Ln^{3+})$  system is firstly discussed by defining the interaction between the neighbors through the potential energy as a function of crystal-field parameters (CFP) [1]. These CFP are functions of charge factors and spherical coordinates of the ligating ions in respect to the central metal ion. The good agreement between X-ray measurements and the simulated structure of solid-state host (crystals, glasses, complexes) brings up the idea of predicting laser crystals as well as highly luminescent systems. The confidence of such simulation procedures depends on what properties the simulated structures could fit [2–7].

In particular, the energy level splitting of  $Ln^{3+}$  ions is an interesting way of testing crystal-field parameter models, because the splitting depends on the local symmetry, i.e., the way the electric field of the first neighbors acts on the luminescent site [8–11].

In this work the splitting of the  ${}^{7}F_{1}$  manifold ( $\Delta E$ ) of the Eu<sup>3+</sup> ion is studied in a series of oxide systems (M<sub>2</sub>O<sub>3</sub> crystals, M = Gd, Y, Lu, In, Sc [12], and in the Al<sub>2</sub>O<sub>3</sub>–SiO<sub>2</sub> glass [13]). The glassy structure is obtained after molecular dynamics simulation. The scalar crystal-field strength parameter [10,11] is obtained using the very well known point charge electrostatic model (PCEM) and the simple overlap model (SOM) [14], in order to explicit that the SOM alters the PCEM predictions in the right sense. The Ref. [15] is revisited in order to corroborate the importance

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of phenomenological crystal-field calculations [16]. For the first time a purely theoretical calculation is developed to confirm the linearity of  $\Delta E$  versus  $N_{\rm V}$  and the simulated glassy structure is used in this kind of calculation.

## 2. Theory

Based on the rotational invariance of the scalar crystalfield strength parameter,  $N_V$ , a model for the degeneracy lift of  $\text{Ln}^{3+}$  ions was developed [10]. The main idea in Ref. [10] is to give a more consistent meaning for the CFP. The maximum splitting of the  $\text{Ln}^{3+}$  manifold,  $\Delta E$ , as a function of  $N_V$  is then obtained as follows:

$$\Delta E = \left[\frac{3g^2}{g(g+2)(g_{\rm a}+1)\pi}\right]^{1/2} \left[\prod_{k} \left|\left\langle J\right\|\sum_{i} C_{(i)}^{(k)}\right\|J\right\rangle\right|\right]^{1/3} N_{\rm V}$$
(1)

In Eq. (1) g is the total degeneracy of the level and  $g_a$  is the degeneracy effectively removed.  $C_{(i)}^{(k)}$  is the Racah spherical tensor (k = 2, 4, 6, and *i* runs over the electrons of the central ion) and J is the total angular momentum associated to the level under investigation.

This complete expression is simplified in the case of discussing the Stark splitting of levels with small J values (say, J = 1 or 3/2), because only k = 2 is to be taken [15].

$$\Delta E = \left[ \frac{g_{\mathrm{a}} \left| \left\langle J \right\| \sum_{i} C^{(2)}(i) \left\| J \right\rangle \right|^{2}}{g(\alpha^{2} + 2)\pi} \right]^{1/2} N_{\mathrm{V}}$$
(2)

For the case of J = 1 (the present case),  $\alpha = 2(E_> - E_a)/\Delta E$  (Eq. (7) of the Ref. [15]).  $E_>$  is the upper sublevel,  $E_a$  is the intermediary sublevel and  $E_<$  is the lower sublevel. Here  $\alpha$  is obtained after the following considerations: the root-mean-square deviation  $(\Delta \epsilon)^2$  of a g-fold degenerate level can be expanded in units of the half the maximum splitting of the level [10]. For J = 1 one has

$$\left(\Delta\epsilon\right)^2 = \Delta E(2+\alpha^2)/2g_{\rm a} \tag{3}$$

But the rms is defined by

$$(\Delta \epsilon)^2 = [(E_b - E_{>})^2 + (E_b - E_a)^2 + (E_b - E_{<})^2]/g_a \qquad (4)$$

 $E_{\rm b}$  is the barycenter of the energy level. Assuming a symmetric repartition of levels, which is reasonable in the series of oxides studied in this work,  $E_{\rm a}$ - $E_{\rm b}$  is negligible compared to the other two terms and the final expression for  $\alpha$  is

$$\alpha = \pm \sqrt{2} \frac{E_{\rm b} - \left(E_{<} + \frac{\Delta E}{2}\right)}{\frac{\Delta E}{2}} \tag{5}$$

The choice of the sign depends on the position of the energy level barycenter, in order to have  $0 < \alpha < 1$ . The calculation of the crystal-field strength parameter  $N_V$  is developed using the PCEM and the SOM [14]. In the PCEM the interacting potential between the metal and

the media is obtained using the valence of the nearest ions, this charge being positioned in the nearest ion site. In the SOM:

- (i) the potential energy due to the presence of the first neighbors is produced by charges uniformly distributed in small regions around the middle Ln–O distance;
- (ii) the charge in these regions is  $-\rho ge$ ,  $\rho$  is proportional to the overlap between the central and ligating ions wave functions.

This leads to

$$B_q^2(\text{SOM}) = \rho [2/(1+\rho)]^3 B_q^2(\text{PCEM})$$
(6)

$$N_{\rm V}(k=2,{\rm SOM}) = \rho[2/(1+\rho)]^3 N_{\rm V}(k=2,{\rm PCEM})$$
 (7)

with[3] 
$$\rho = \rho_0 (R_0/R)^{3.5}$$
 (8)

 $\rho_0$  is 0.05, the maximum overlap [17], and  $R_0$  is the smaller Ln–O distance.

Numerical simulations using the molecular dynamics technique have been performed in order to obtain the microscopic structure of an alumino-silicate glass. Simulations details are presented in a previous paper [13].

#### 3. Results and discussion

The spherical coordinates of all oxide crystals were taken from Ref. [12]. In the case of the glass, one has dealt with and average of 72 different sites. For each site, the  $B_q^k$  and  $\Delta E$  values were calculated. The charge factor which enter in the CFP expressions is 2, the valence of the oxygen ion, in the PCEM and there are two situations for the SOM: firstly the charge factor varies in order to reproduce the experimental splitting (a phenomenological procedure: Theo-Phen case); secondly the charge factor is the valence of the oxygen ion (Theo case).

The calculation of the  $\Delta E$  using the PCEM is the first interesting result (Fig. 1). For the sake of comparison the  $\Delta E$  experimental values were associated to the same  $N_V$ values. Quantitatively, there is a mismatch between the PCEM predictions and the experimental  ${}^7F_1$  level splitting, but the behavior of  $\Delta E$  as a function of the  $N_V$  is linear. The magnitude of the PCEM predictions is around three times stronger than the measurements. The Fig. 2 shows that this difference is satisfactorily suppressed by the SOM factor.

In the Fig. 2 all results of  $\Delta E$  versus  $N_V$  after applying different methods are shown. The experimental and phenomenological results are from Ref. [15]. For the theoretical predictions (Theo curves) the spherical coordinates and valence of the oxygen ions were input in the  $N_V$  expressions. In the Theo-Phen case it is used the phenomenological charge factor. The linearity as well as the similarity in respect to the phenomenological results from the Ref. [15] can be readily noted. In the case of the glass, the result is in the lower side of the linear curve (black star), with a pheDownload English Version:

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